

FMBTRC120SS-Q1

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FMBTRC120SS-Q1

NPN Silicon Epitaxial Planar Digital Transistor

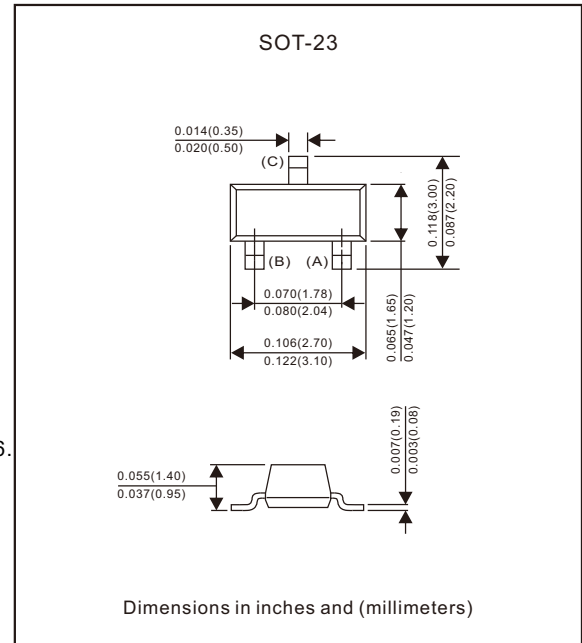
Features

- For Switching and interface circuit and drive circuit applications.
- With built-in bias resistors.
- Simplify circuit design.
- Reduce a quantity of parts and manufacturing process.
- Qualified to AEC-Q101 standards for high reliability.
- We declare that the material of product compliance with RoHS requirements.
- Suffix "-H" indicates Halogen free parts, ex. FMBTRC120SS-Q1-H.

Mechanical data

- Epoxy:UL94-V0 rated flame retardant.
- Case : Molded plastic, SOT-23.
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026.
- Mounting Position : Any.

Package outline



Maximum ratings (At $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Output voltage	V_O	50	V
Input voltage	V_I	30 to -10	V
Output current	I_O	100	mA
Total power dissipation	P_{tot}	200	mW
Junction temperature	T_j	150	$^{\circ}\text{C}$
Storage temperature range	T_{stg}	-55 to +150	$^{\circ}\text{C}$

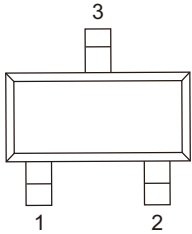
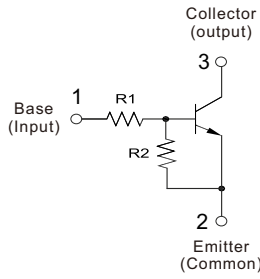
Electrical characteristics (At $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit
DC current gain	$V_O=5\text{V}$, $I_O=10\text{mA}$	h_{FE}	24			
Output cutoff current	$V_O=50\text{V}$	$I_{O(OFF)}$			500	nA
Input current	$V_I=5\text{V}$	I_I			0.88	mA
Output voltage	$I_O=10\text{mA}$, $I_I=0.5\text{mA}$	$V_{O(ON)}$			0.3	V
Input on voltage (ON)	$V_O=0.3\text{V}$, $I_O=2\text{mA}$	$V_{I(ON)}$			3.0	V
Input off voltage (OFF)	$V_O=5\text{V}$, $I_O=100\mu\text{A}$	$V_{I(OFF)}$	0.8			V
Transition frequency	$V_O=10\text{V}$, $I_O=5\text{mA}$	$f_T^{(1)}$		250		MHz
Input resistance		R_1		10		K Ω
Base Emitter resistance		R_2		4.7		K Ω

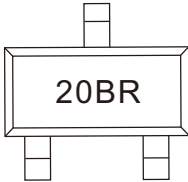
Note: 1.Characteristic of transistor only.

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Pinning information

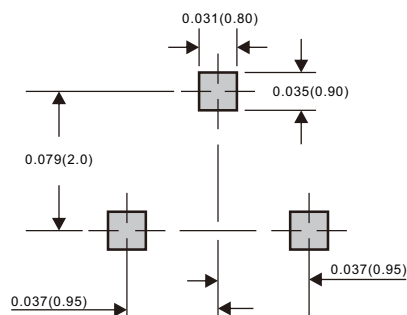
Pin	Simplified outline	Symbol
Pin1 Base Pin2 Emitter Pin3 Collector		

Marking

Type numbe	Marking code
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Suggested solder pad layout

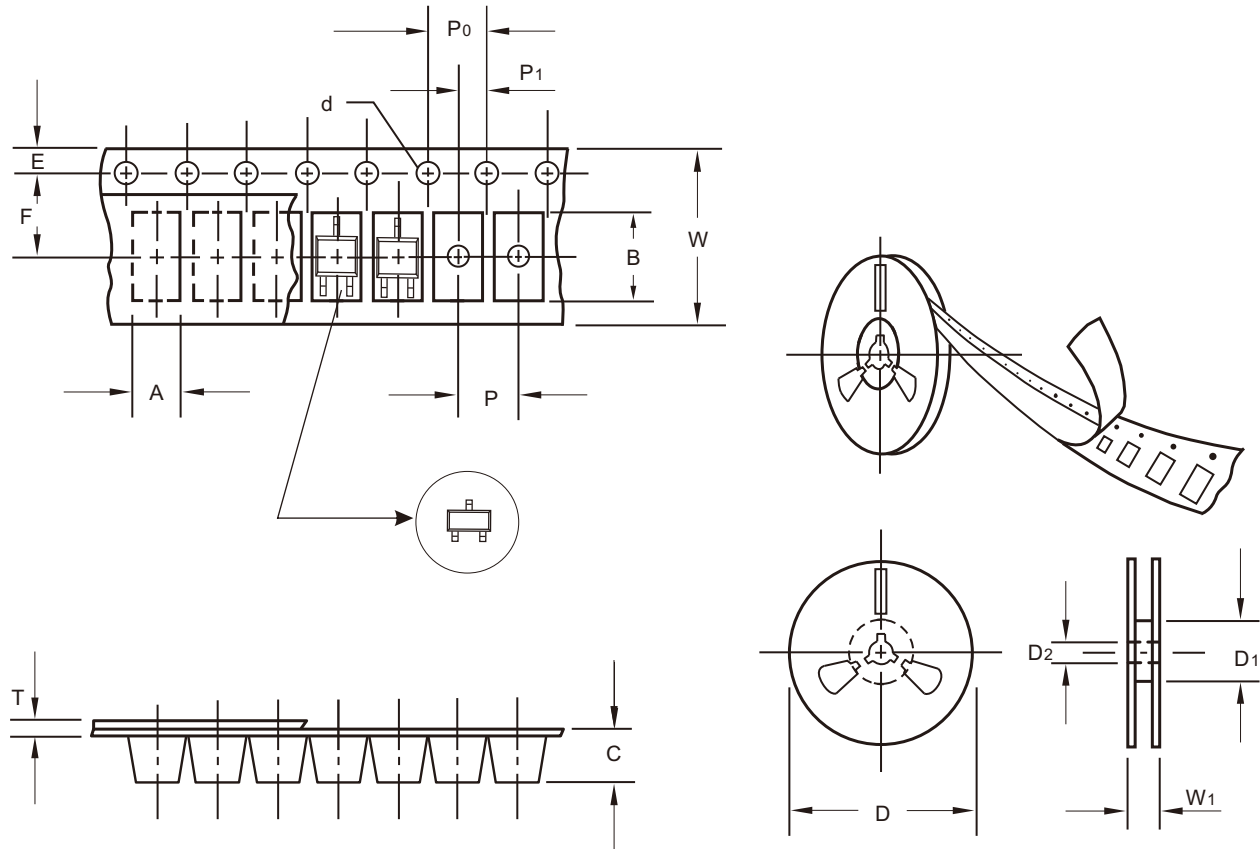
SOT-23



Dimensions in inches and (millimeters)

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Packing information



unit:mm

Item	Symbol	Tolerance	SOT-23
Carrier width	A	0.1	3.15
Carrier length	B	0.1	2.77
Carrier depth	C	0.1	1.22
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	55.00
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	12.0

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

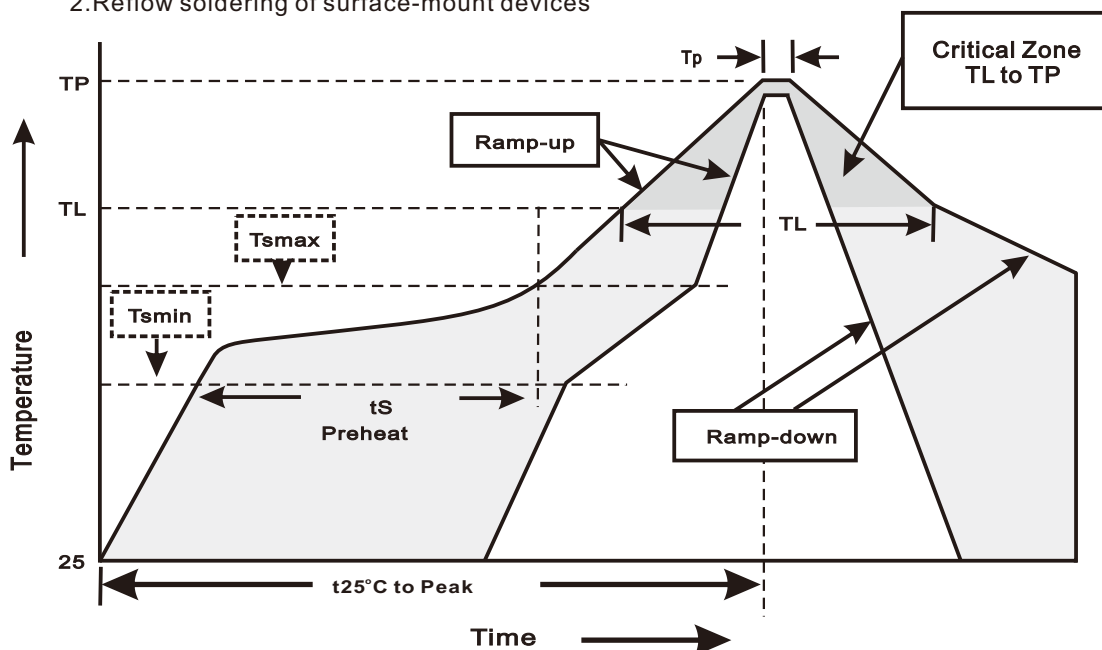
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SOT-23	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000	11.6

Suggested thermal profiles for soldering processes

- 1.Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- 2.Reflow soldering of surface-mount devices



3.Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T _L to T _P)	<3°C/sec
Preheat -Temperature Min(T _{smmin}) -Temperature Max(T _{smmax}) -Time(min to max)(t _s)	150°C 200°C 60~120sec
T _{smmax} to T _L -Ramp-upRate	<3°C/sec
Time maintained above: -Temperature(T _L) -Time(t _L)	217°C 60~260sec
Peak Temperature(T _P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t _p)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes